Low-power dual 2-input NAND Schmitt trigger Rev. 8 — 3 July 2017

Product data sheet

General description 1

The 74AUP2G132 provides the dual 2-input NAND Schmitt trigger function which accepts standard input signals. They can transform slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H.

Features and benefits 2

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5 000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1 000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications 3

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator

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Low-power dual 2-input NAND Schmitt trigger

4 Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP2G132DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1					
74AUP2G132GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm	SOT833-1					
74AUP2G132GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm	SOT1089					
74AUP2G132GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm	SOT902-2					
74AUP2G132GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm	SOT1116					
74AUP2G132GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm	SOT1203					
74AUP2G132GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm	SOT1233					

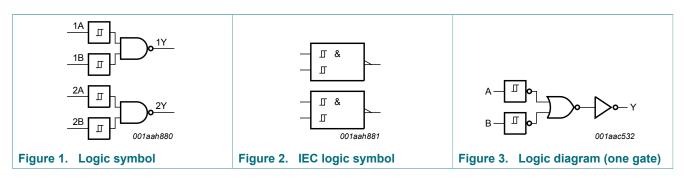
5 Marking

Table 2. Marking codes							
Type number	Marking code ^[1]						
74AUP2G132DC	aE2						
74AUP2G132GT	aE2						
74AUP2G132GF	aE						
74AUP2G132GM	aE2						
74AUP2G132GN	aE						
74AUP2G132GS	aE						
74AUP2G132GX	aE						

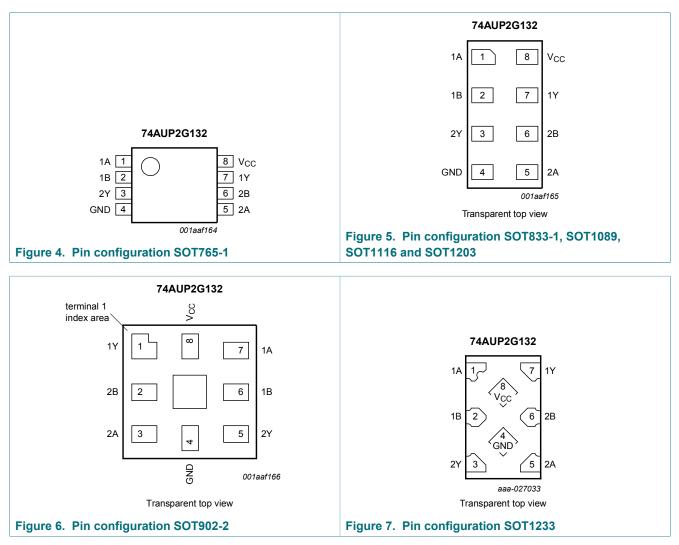
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

Low-power dual 2-input NAND Schmitt trigger

6 Functional diagram



7 Pinning information



7.1 Pinning

Low-power dual 2-input NAND Schmitt trigger

7.2 Pin description

Symbol	Pin	Pin				
	SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233	SOT902-2				
1A, 2A	1, 5	7, 3	data input			
1B, 2B	2, 6	6, 2	data input			
GND	4	4	ground (0 V)			
1Y, 2Y	7, 3	1, 5	data output			
V _{CC}	8	8	supply voltage			

8 Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input		Output
nA	nB	nY
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

Low-power dual 2-input NAND Schmitt trigger

Limiting values 9

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed. For VSSOP8 packages: above 110 $^{\circ}$ C the value of P_{tot} derates linearly with 8.0 mW/K. [1]

[2] For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

For X2SON8 package: above 118 °C the value of P_{tot} derates linearly with 7.7 mW/K.

10 Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V_{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

Low-power dual 2-input NAND Schmitt trigger

11 Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
r _{amb} = 25	°C			,		
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
V _{OL} L(I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	0.31	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.31	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.44	V
lı	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	40	μA
CI	input capacitance	V_{I} = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF

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Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		$I_{\rm O}$ = -20 $\mu \text{A};V_{\rm CC}$ = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
Teamb = -40 VOH F VOL F I II IOFF F		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.7 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		$I_{\rm O}$ = 2.3 mA; $V_{\rm CC}$ = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.33	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI_{OFF}	additional power-off leakage current			±0.6	μA	
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
Δl _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	50	μA

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Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +125 °C				1	
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.6 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		$I_{\rm O}$ = 2.3 mA; $V_{\rm CC}$ = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.36	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.50	V
l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

Low-power dual 2-input NAND Schmitt trigger

12 Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 9.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	Unit		
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pF	` 								
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	22.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	16.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	8.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	6.2	ns
C _L = 10 p	F		1		1		1	1	
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	19.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	9.9	ns
		V_{CC} = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	7.2	ns
C _L = 15 p	F		1	1		1		1	
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	29.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	21.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	11.0	ns
		V_{CC} = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	8.0	ns
	1	1		1	1	1	1	1	

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Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 30 p	F								
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	39.9	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	14.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	10.1	ns
C _L = 5 pF	, 10 pF, 15 pF and 3	0 pF							
C _{PD}	power dissipation	f_i = 1 MHz; V_I = GND to V_{CC} ^[3]							
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	pF

[1] [2] [3]

All typical values are measured at nominal V_{CC}. t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in µW). $P_D = C_{PD} x V_{CC}^2 x f_i x N + \Sigma(C_L x V_{CC}^2 x f_0)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

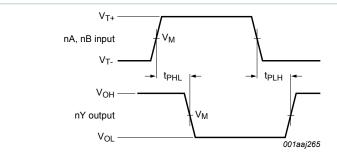
V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

Low-power dual 2-input NAND Schmitt trigger

12.1 Waveforms and test circuit



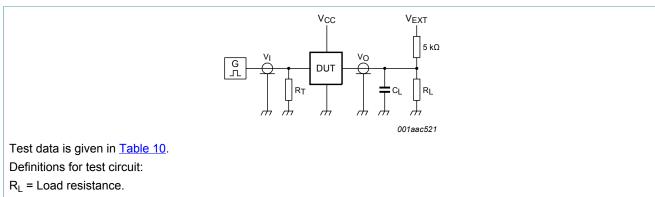
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 8. The data input (nA or nB) to output (nY) propagation delays

Table 9. Measuremer	nt points	s
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Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	$t_r = t_f$
0.8 V to 3.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns



C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Figure 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L ^[1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 x V _{CC}

[1] $R_L = 5 k\Omega$ when measuring enable and disable times. $R_L = 1 M\Omega$ when measuring propagation delays, setup and hold times and pulse width.

Low-power dual 2-input NAND Schmitt trigger

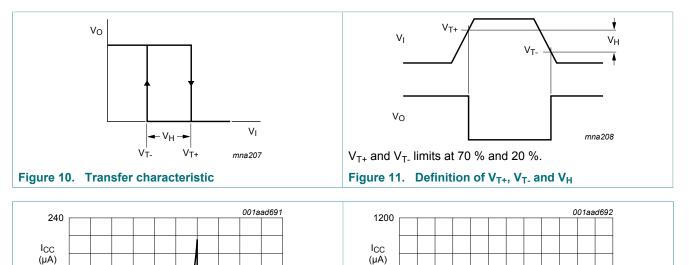
13 Transfer characteristics

Table 11. Transfer characteristics

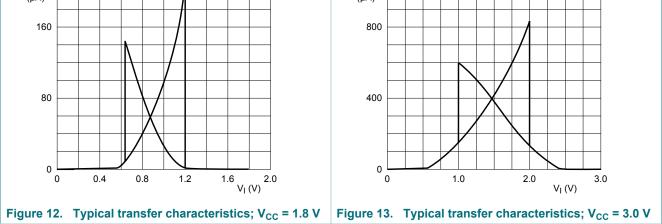
Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 9.

Symbol Parameter		Conditions	Tai	T _{amb} = 25 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	
V _{T+}	V _{T+} positive-going threshold voltage	see <u>Figure 10</u> and <u>Figure 11</u>							
		V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.62	V
		V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	2.32	V
V _{T-}	negative-going threshold voltage	see <u>Figure 10</u> and Figure 11							
		V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	1.24	V
V _H hysteresis voltage	$(V_{T+} - V_{T-})$; see Figure 10, Figure 11, Figure 12 and Figure 13								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	1.31	V

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13.1 Waveforms transfer characteristics



Low-power dual 2-input NAND Schmitt trigger

14 Application information

The slow input rise and fall times cause additional power dissipation which can be calculated using the following formula:

 $P_{add} = f_i x (t_r \times \Delta I_{CC(AV)} + t_f x \Delta I_{CC(AV)}) x V_{CC}$ where:

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$ = average additional supply current (µA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 14.

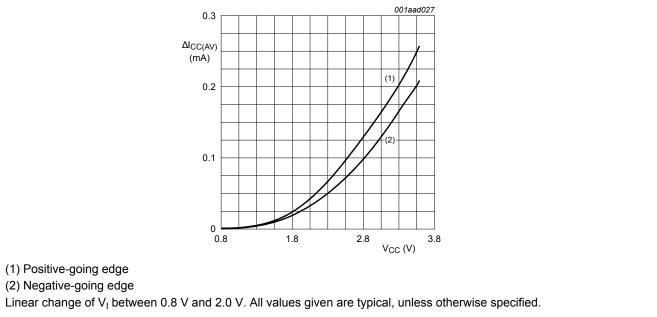


Figure 14. Average I_{CC} as a function of V_{CC}

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15 Package outline

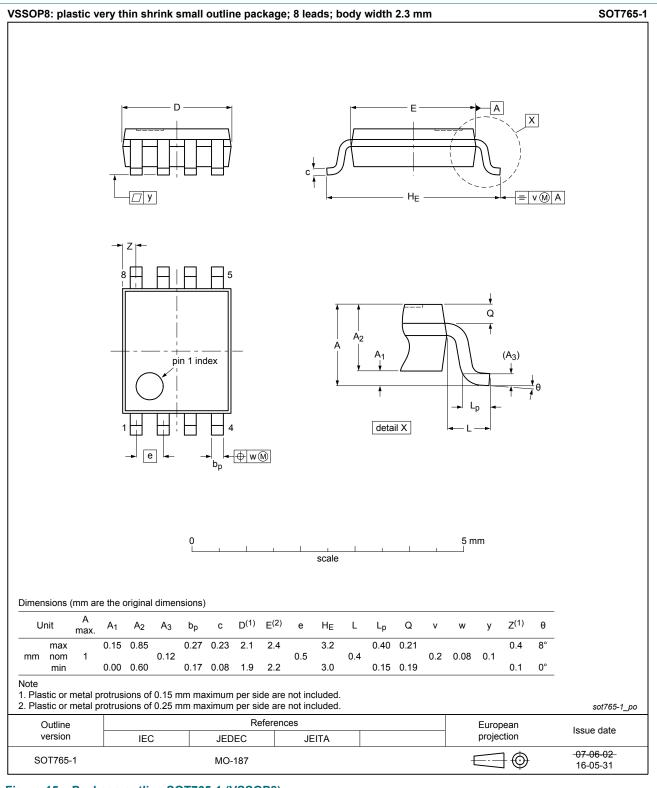
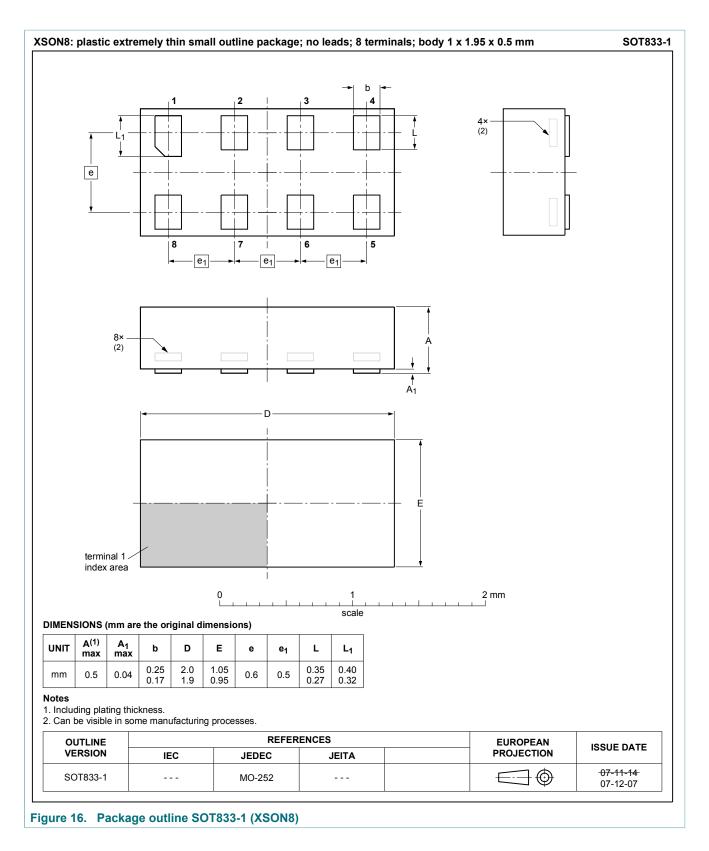


Figure 15. Package outline SOT765-1 (VSSOP8)

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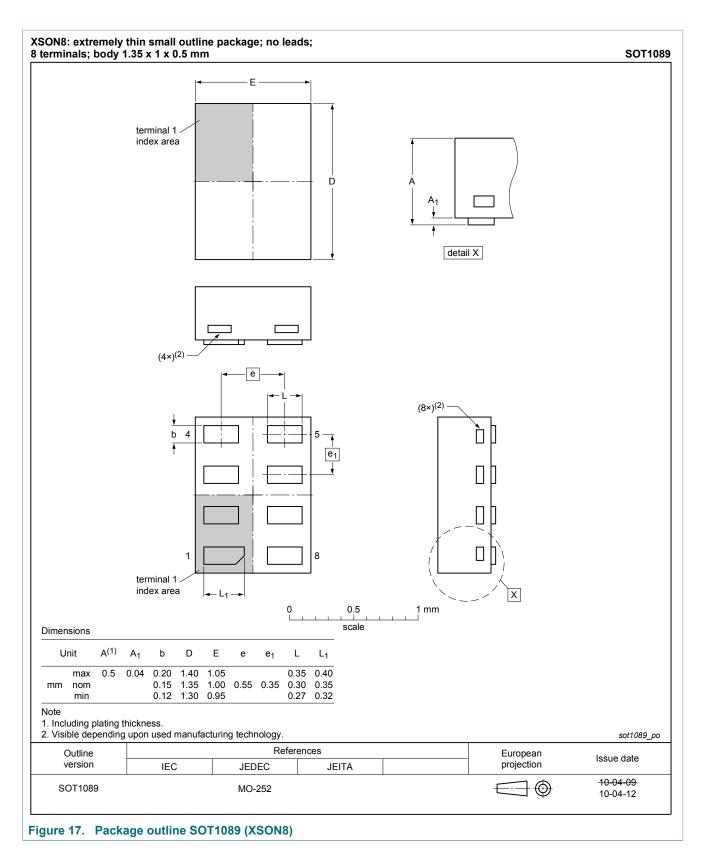
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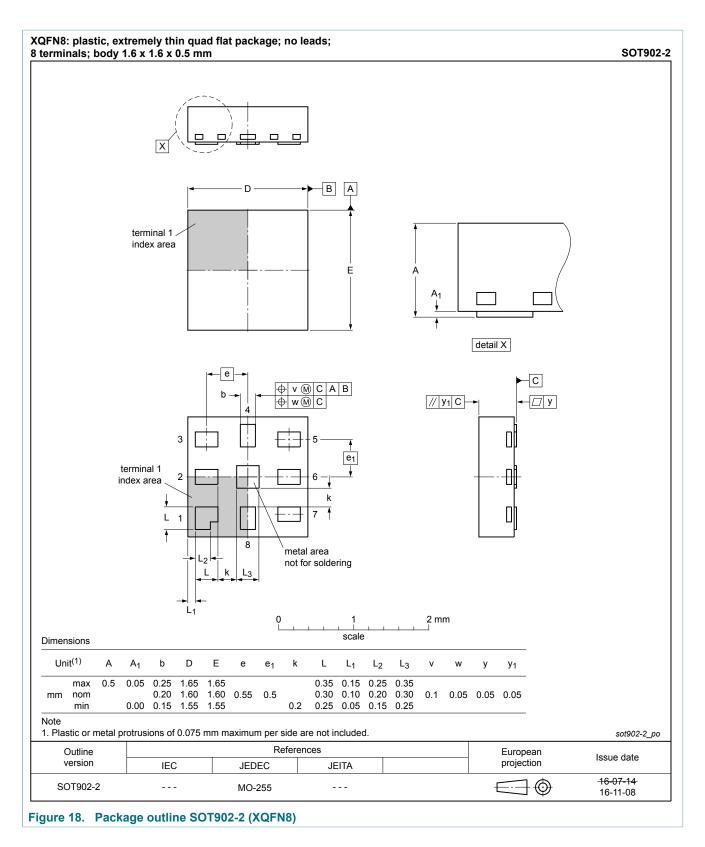
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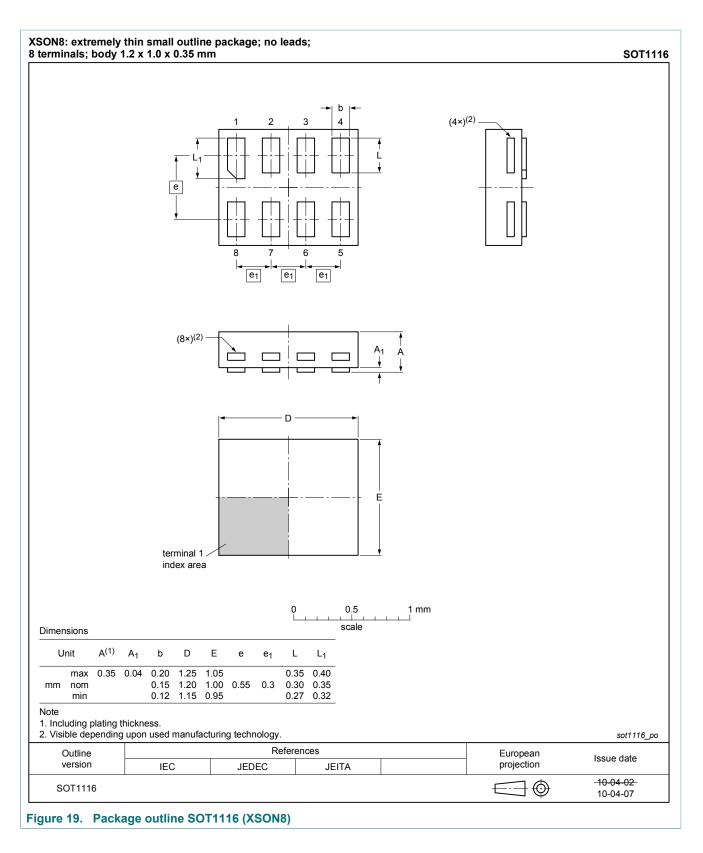


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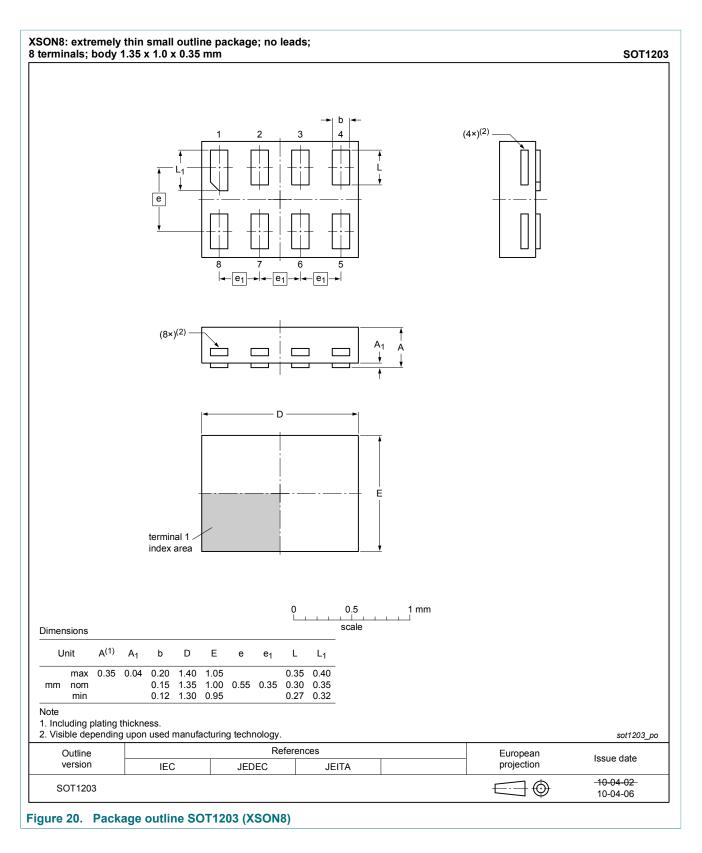
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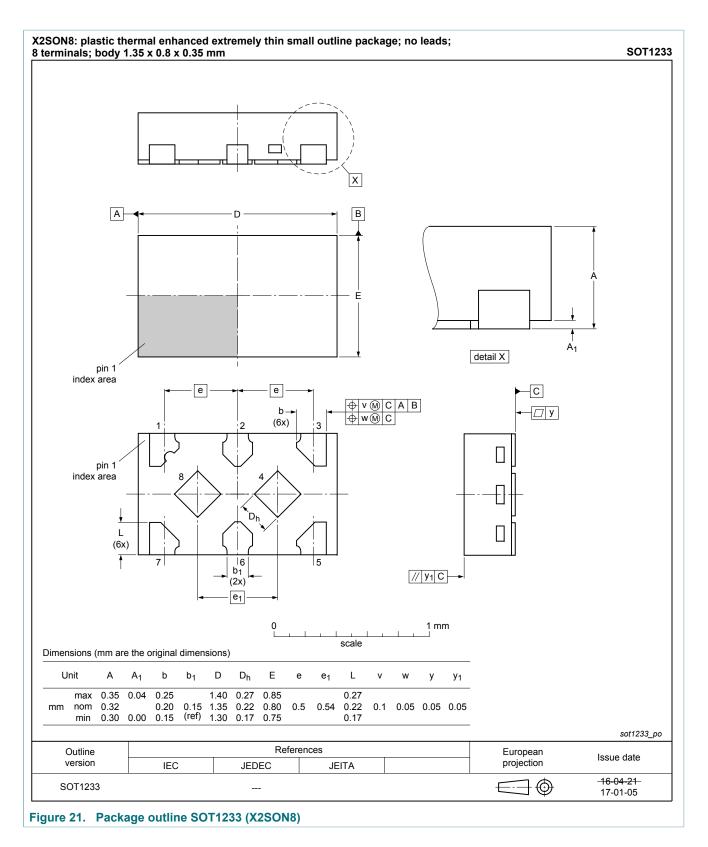
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16 Abbreviations

Table 12. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
ММ	Machine Model			

17 Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G132 v.8	20170703	Product data sheet	-	74AUP2G132 v.7
Modifications:	Nexperia. • Legal texts hav • Type number 7	nis data sheet has been redesig e been adapted to the new con 4AUP2G132GX (SOT1233 / X 4AUP2G132GD removed.	npany name where	
74AUP2G132 v.7	20130208	Product data sheet	-	74AUP2G132 v.6
Modifications:	For type number	er 74AUP2G132GD XSON8U h	has changed to XSC	N8.
74AUP2G132 v.6	20120803	Product data sheet	-	74AUP2G132 v.5
74AUP2G132 v.5	20111201	Product data sheet	-	74AUP2G132 v.4
74AUP2G132 v.4	20101104	Product data sheet	-	74AUP2G132 v.3
74AUP2G132 v.3	20081215	Product data sheet	-	74AUP2G132 v.2
74AUP2G132 v.2	20080314	Product data sheet	-	74AUP2G132 v.1
74AUP2G132 v.1	20061018	Product data sheet	-	-

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18 Legal information

18.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Ordering information	2
5	Marking	
6	Functional diagram	
7	Pinning information	
7.1	Pinning	
7.2	Pin description	
8	Functional description	
9	Limiting values	
10	Recommended operating conditions	5
11	Static characteristics	
12	Dynamic characteristics	9
12.1	Waveforms and test circuit	11
13	Transfer characteristics	12
13.1	Waveforms transfer characteristics	13
14	Application information	
15	Package outline	
16	Abbreviations	22
17	Revision history	
18	Legal information	

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